



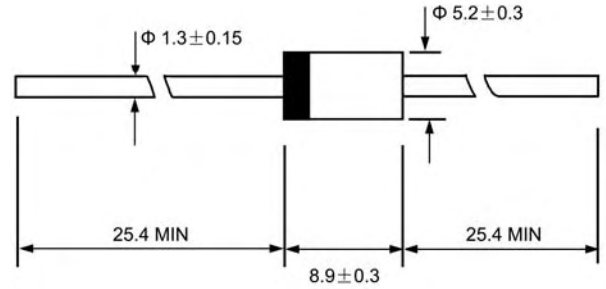
Features

- ◇ Metal-Semiconductor junction with guard ring
- ◇ Epitaxial construction
- ◇ Low forward voltage drop, low switching losses
- ◇ High surge capability
- ◇ For use in low voltage, high frequency inverters free wheeling, and polarity protection applications
- ◇ The plastic material carries U/L recognition 94V-0

Mechanical Data

- ◇ Case: JEDEC DO-27, molded plastic
- ◇ Terminals: Axial lead, solderable per MIL-STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.041 ounces, 1.15 grams
- ◇ Mounting position: Any

DO - 27



Dimensions in millimeters

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

| | | SB320 | SB330 | SB340 | SB350 | SB360 | SB370 | UNITS |
|---|-----------------|--------------|-------|-------|--------------|-------|-------|-------|
| Maximum recurrent peak reverse voltage | V_{RRM} | 20 | 30 | 40 | 50 | 60 | 70 | V |
| Maximum RMS voltage | V_{RMS} | 14 | 21 | 28 | 35 | 42 | 49 | V |
| Maximum DC blocking voltage | V_{DC} | 20 | 30 | 40 | 50 | 60 | 70 | V |
| Maximum average forward rectified current 9.5mm lead length, (see fig.1) | $I_{F(AV)}$ | 3.0 | | | | | | A |
| Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ\text{C}$ | I_{FSM} | 80.0 | | | | | | A |
| Maximum instantaneous forward voltage @ 3.0 A (Note 1) | V_F | 0.5 | | | 0.74 | | | V |
| Maximum reverse current @ $T_A=25^\circ\text{C}$ at rated DC blocking voltage @ $T_A=100^\circ\text{C}$ | I_R | 0.5 | | | 10.0 | | | mA |
| | | 20.0 | | | | | | |
| Typical junction capacitance (Note2) | C_J | 40 | | | | | | pF |
| Typical thermal resistance (Note3) | $R_{\theta JA}$ | 40 | | | | | | °C/W |
| Operating junction temperature range | T_J | -55 --- +125 | | | -55 --- +150 | | | °C |
| Storage temperature range | T_{STG} | -55 --- +150 | | | | | | °C |

NOTE: 1. Pulse test : 300 μ s pulse width, 1% duty cycle.
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
3. Thermal resistance junction to ambient

Ratings AND Characteristic Curves

FIG.1 -- FORWARD CURRENT DERATING CURVE

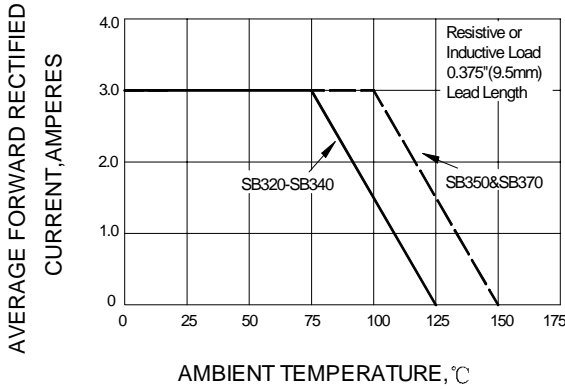


FIG.2 --MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

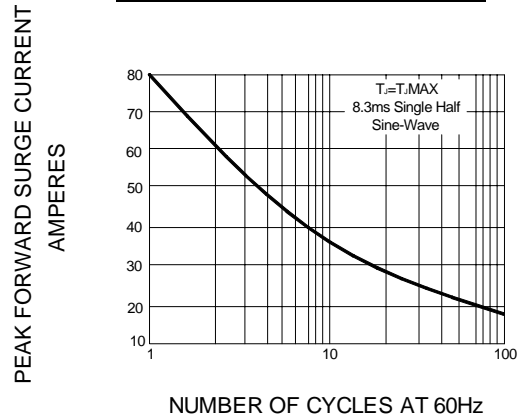


FIG.3 --TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

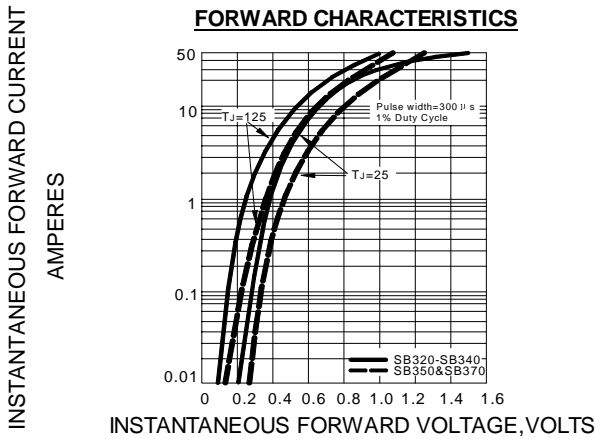


FIG.4--TYPICAL REVERSE CHARACTERISTICS

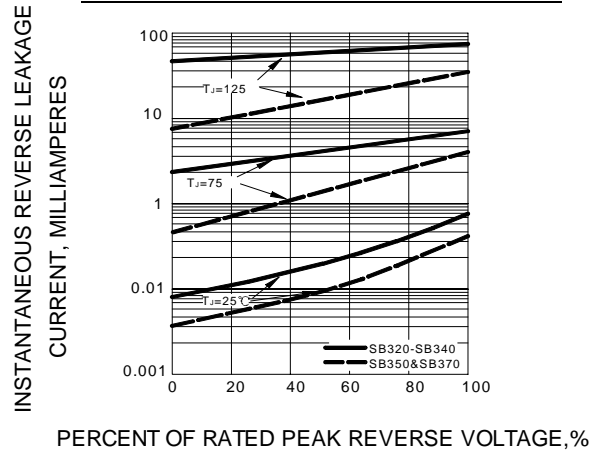


FIG.5--TYPICAL JUNCTION CAPACITANCE

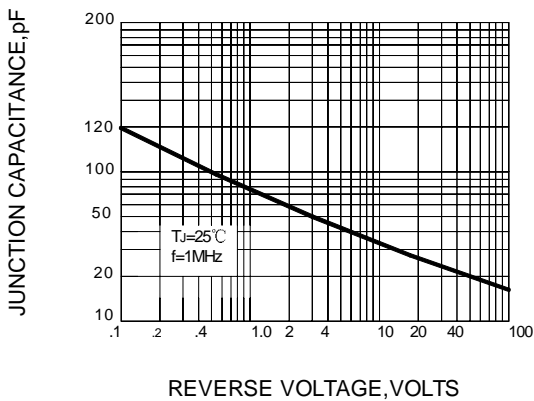


FIG.6--TYPICAL TRANSIENT THERMAL IMPEDANCE

